

Provisional Data

## Insulated Gate Bi-Polar Transistor Type T1200EA45E

### Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
$V_{CES}$	Collector – emitter voltage	4500	V
$V_{DC link}$	Permanent DC voltage for 100 FIT failure rate	2800	V
$V_{GES}$	Peak gate – emitter voltage	±20	V

	RATINGS	MAXIMUM LIMITS	UNITS
$I_{C(DC)}$	Continuous DC collector current, IGBT (Note 4)	2132	A
$I_{CRM}$	Repetitive peak collector current, $t_p=500\mu s$ , IGBT	2.1	kA
$I_{ECO}$	Maximum reverse emitter current, $t_p=1ms$ , (note 2 & 3)	1193	A
$P_{MAX}$	Maximum power dissipation, IGBT (note 4)	11.1	kW
$T_{j op}$	Operating temperature range	-40 to +125	°C
$T_{stg}$	Storage temperature range	-40 to +125	°C

Notes: -

- 1) Unless otherwise indicated  $T_c = 125^\circ C$
- 2)  $T_{sink} = 55^\circ C$ , double side cooled
- 3) The Use of an anti-parallel diode is recommended
- 4)  $T_{sink} = 25^\circ C$ , double side cooled

## Characteristics

### IGBT Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
$V_{CE(sat)}$	Collector – emitter saturation voltage	-	3.5	3.8	$I_C = 1200A, V_{GE} = 15V, T_j = 25^\circ C$	V
		-	4.7	5.0	$I_C = 1200A, V_{GE} = 15V$	V
$V_{T0}$	Threshold voltage	-	-	1.8	Current range: 400 – 1200A	V
$r_T$	Slope resistance	-	-	1.6		$m\Omega$
$V_{GE(TH)}$	Gate threshold voltage	4.7	5.5	6.4	$V_{CE} = V_{GE}, I_C = 200mA$	V
$I_{CES}$	Collector – emitter cut-off current	-	14	25	$V_{CE} = V_{CES}, V_{GE} = 0V$	mA
$I_{GES}$	Gate leakage current	-	-	$\pm 200$	$V_{GE} = \pm 20V$	$\mu A$
$C_{ies}$	Input capacitance	-	200	-	$V_{CE} = 25V, V_{GE} = 0V, f = 1MHz$	nF
$t_{d(on)}$	Turn-on delay time	-	1.7	-	$I_C = 1200A, V_{CE} = 0.5V_{CES},$ $V_{GE} = \pm 20V,$	$\mu s$
$t_r(l)$	Rise time	-	2.8	-		$\mu s$
$Q_{g(on)}$	Turn-on gate charge	-	-	120	$R_{g(ON)} = 3.3\Omega,$ $R_{g(OFF)} = 2\Omega,$	$\mu C$
$E_{on}$	Turn-on energy	-	3.2	-		J
$t_{d(off)}$	Turn-off delay time	-	1.4	-	$R_{g(OFF)} = 2\Omega,$	$\mu s$
$t_f$	Fall time	-	1.7	-		$\mu s$
$Q_{g(off)}$	Turn-off gate charge	-	-	140		$\mu C$
$E_{off}$	Turn-off energy	-	3.8	-		J

### Thermal Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
$R_{thJK}$	Thermal resistance junction to sink, IGBT	-	-	9	Double side cooled	K/kW
		-	-	14	Collector side cooled	K/kW
		-	-	25	Emitter side cooled	K/kW
F	Mounting force	25	30	35	Note 2	kN
$W_i$	Weight	-	1.2	-		kg

#### Notes:-

- 1) Unless otherwise indicated  $T_j = 125^\circ C$
- 2) For other clamp forces, please consult factory

**Curves**

Figure 1 – Typical collector-emitter saturation voltage characteristics

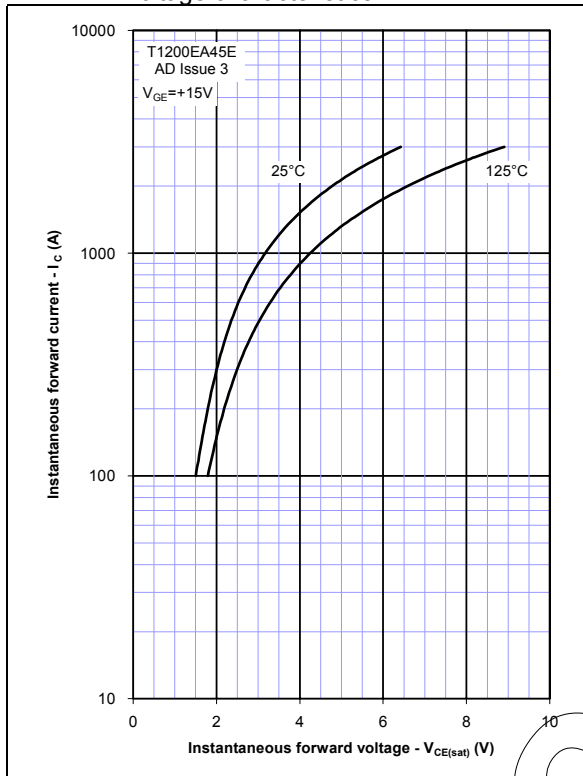


Figure 2 – Typical output characteristic

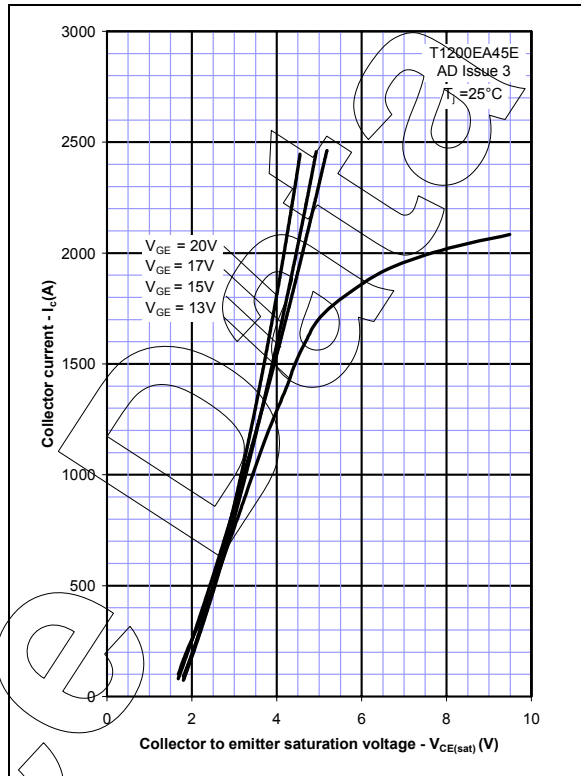


Figure 3 – Typical output characteristic

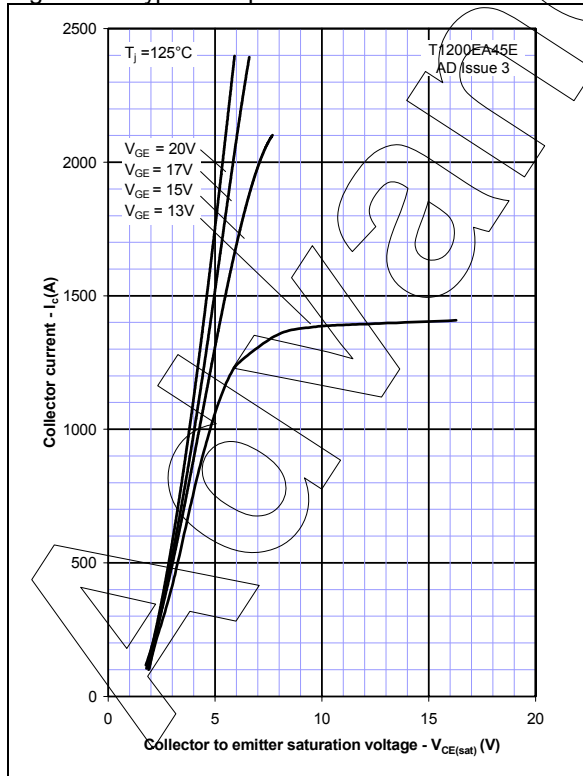


Figure 4 – Typical turn-on gate charge

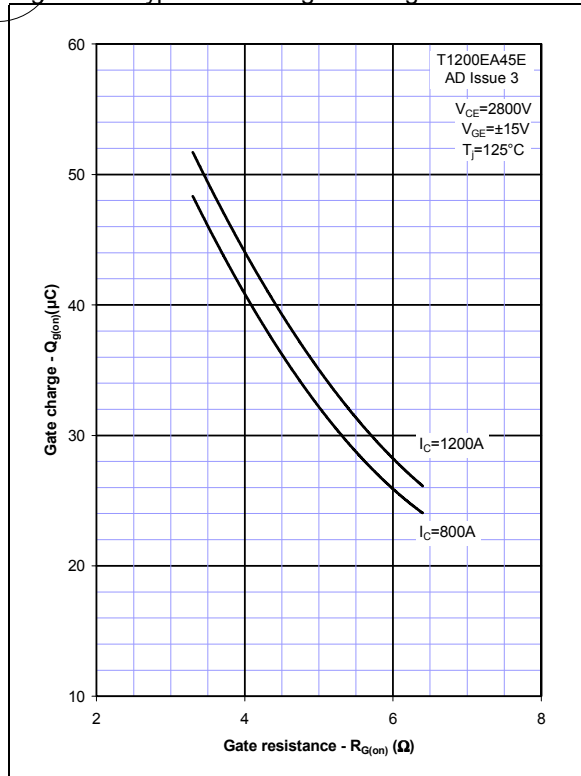


Figure 5 – Typical turn-off gate charge

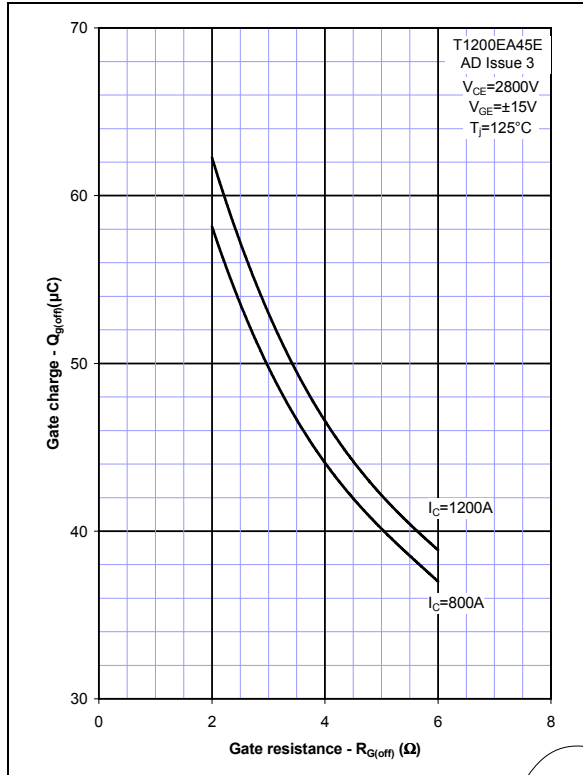


Figure 6 – Typical turn-on delay time vs gate resistance

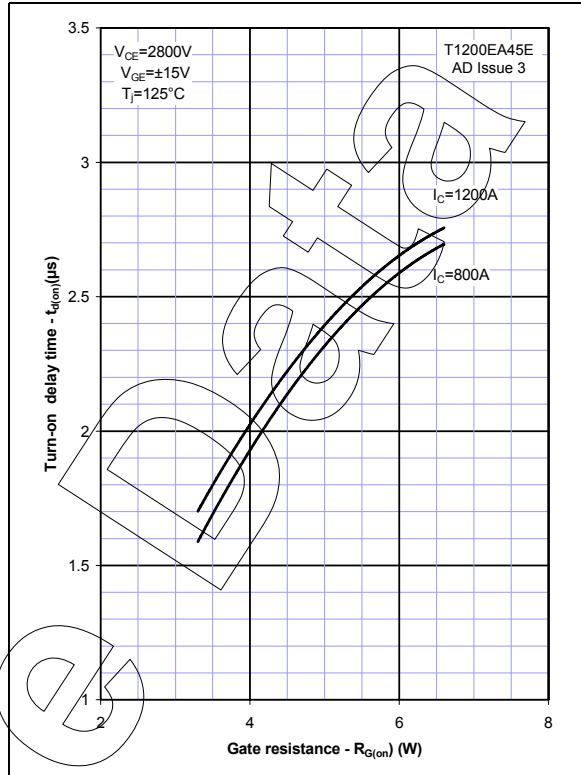


Figure 7 – Typical turn-off delay time vs. gate resistance

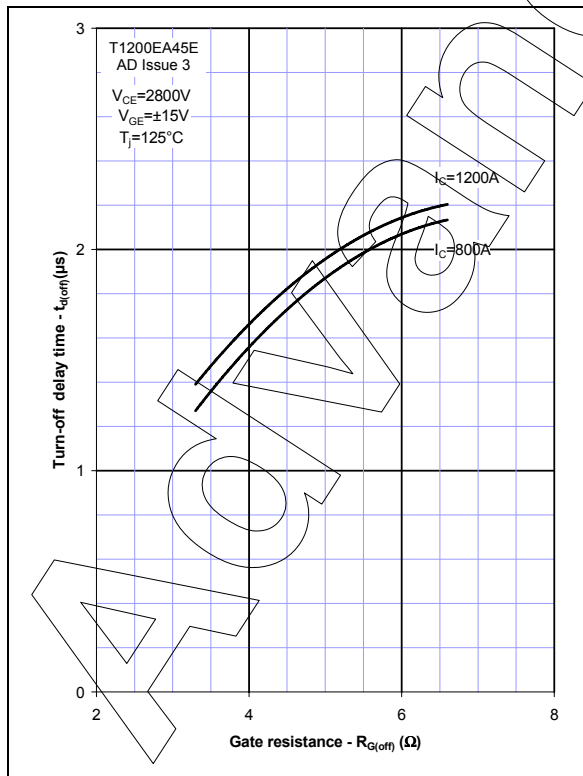


Figure 8 – Typical turn-on energy vs. collector current

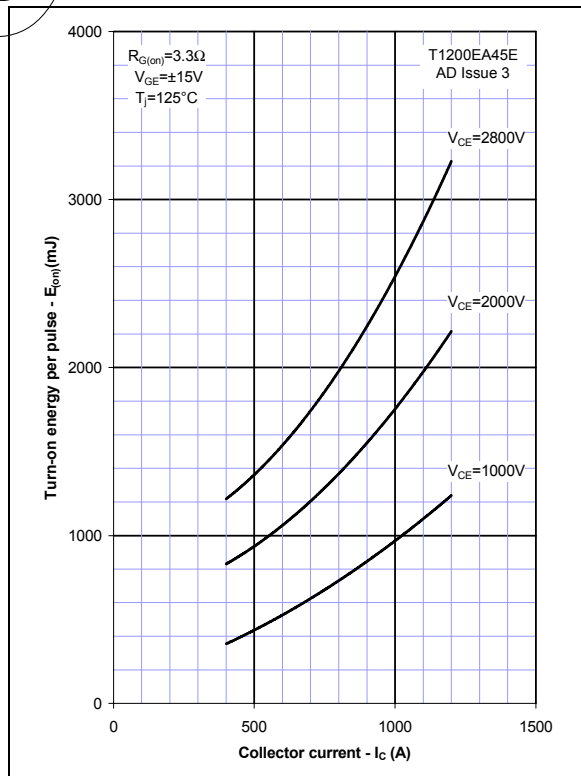


Figure 9 – Typical turn-on energy vs. di/dt

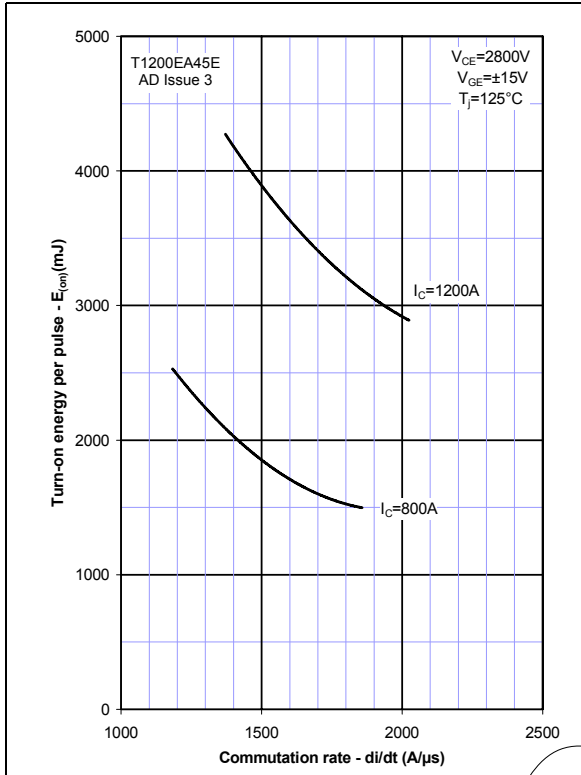


Figure 10 – Typical turn-off energy vs. collector current

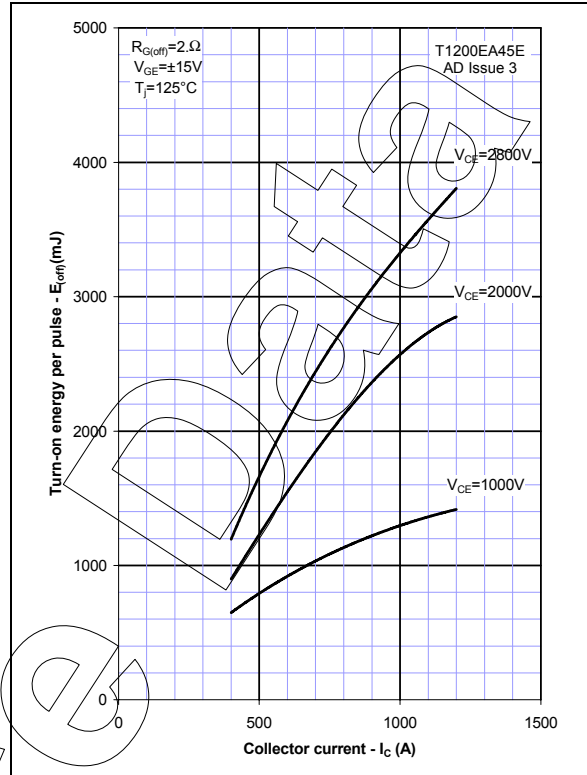


Figure 11 – Turn-off energy vs voltage

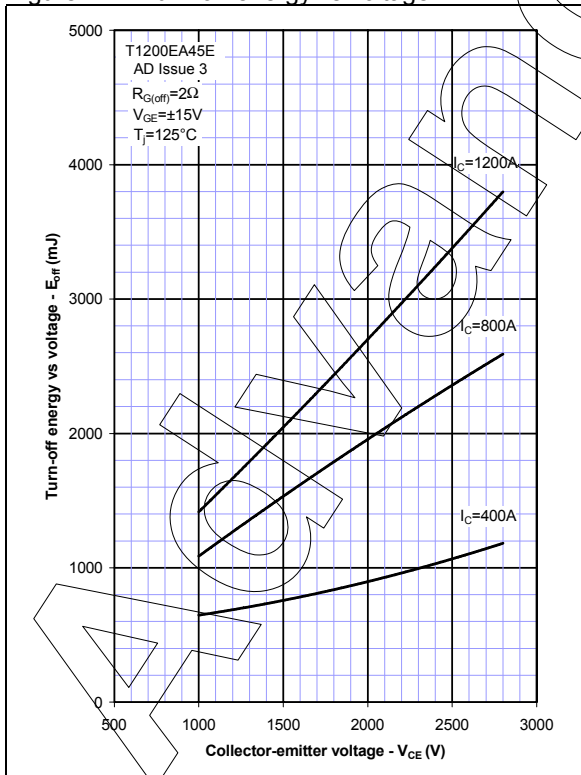


Figure 12 – Safe operating area

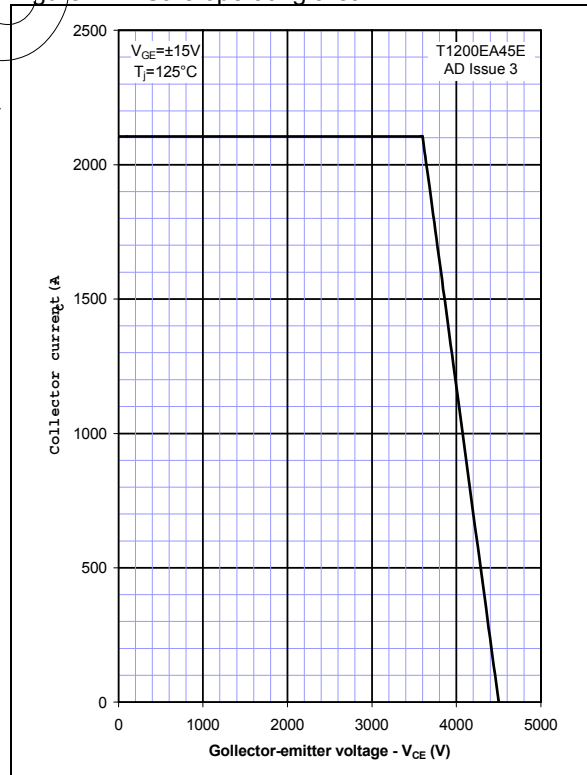
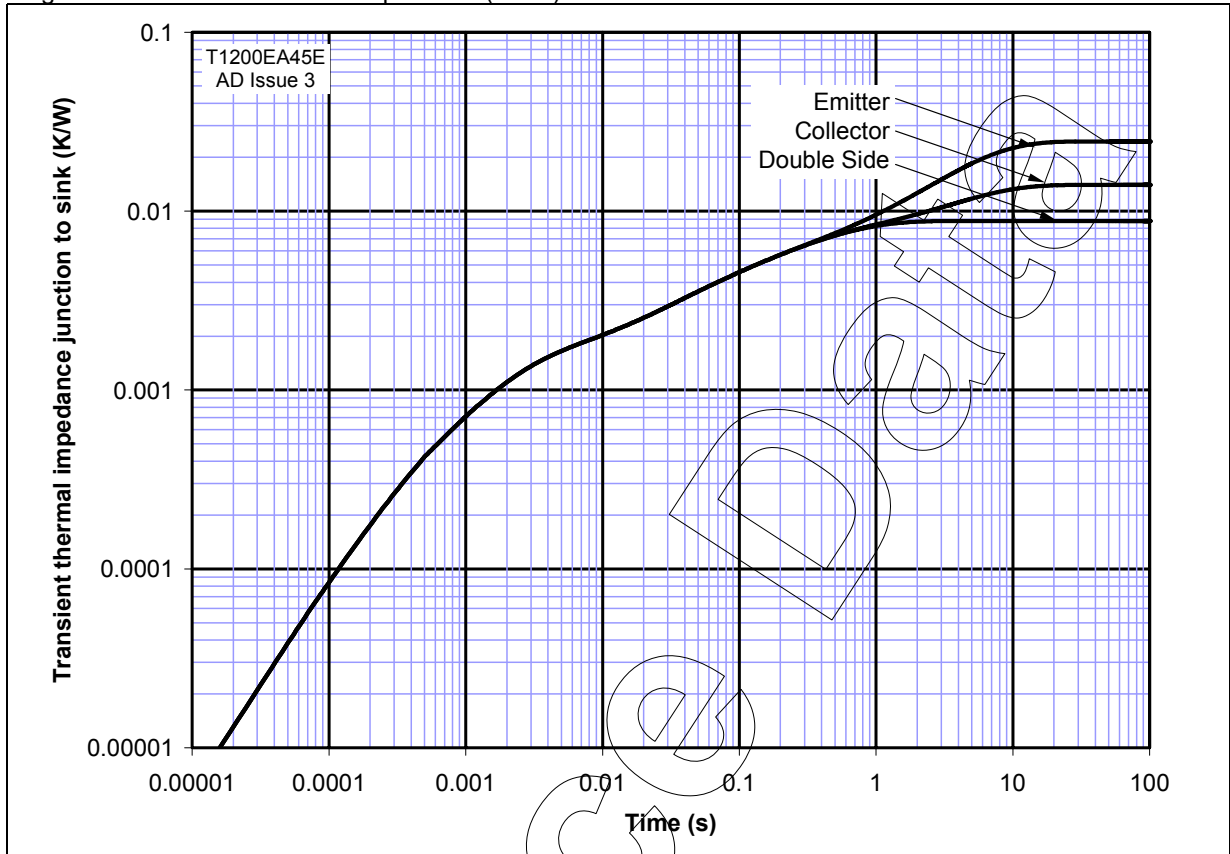
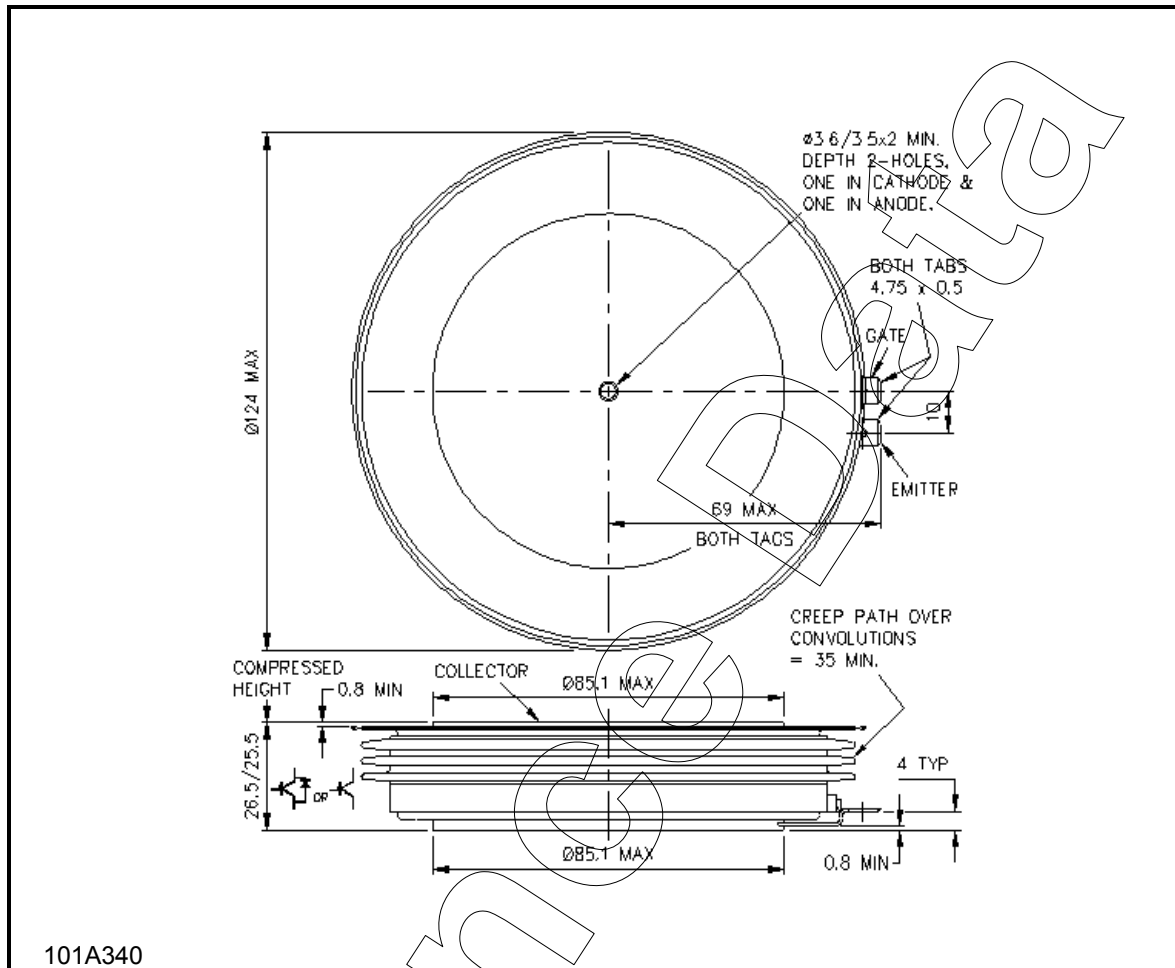


Figure 13 – Transient thermal impedance (IGBT)



**Outline Drawing & Ordering Information**



101A340

**ORDERING INFORMATION**

(Please quote 10 digit code as below)

<b>T1200</b>	<b>EA</b>	<b>45</b>	<b>E</b>
Fixed type Code	Fixed Outline Code	Voltage Grade $V_{CES}/100$ 45	Fixed format code

Typical order code: T1200EA54E ( $V_{CES} = 4500V$ )

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